

SMALL SIGNAL COMPLEMENTARY PRE-BIASED DUAL TRANSISTOR
Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Surface Mount Package Suited for Automated Assembly
- **Totally Lead-Free & Fully RoHS compliant (Note 1)**
- **Halogen and Antimony Free. "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Part Number	R1 (NOM)	R2 (NOM)
DCX124EU	22K Ω	22K Ω
DCX144EU	47K Ω	47K Ω
DCX114YU	10K Ω	47K Ω
DCX123JU	2.2K Ω	47K Ω
DCX114EU	10K Ω	10K Ω
DCX143EU	4.7K Ω	4.7K Ω

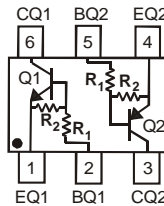
Mechanical Data

- Case: SOT363
- Case material: Molded Plastic. "Green" Molding Compound.
- Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.006 grams (approximate)

Part Number	R1 Only
DCX143TU	4.7K Ω
DCX114TU	10K Ω



Top View



R1, R2



R1 Only

Device Schematic

Ordering Information (Note 3 & 4)

Product	Grade	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DCX124EU-7-F	Commercial	C17	7	8	3,000
DCX124EUQ-7-F	Automotive	C17	7	8	3,000
DCX124EUQ-13-F	Automotive	C17	13	8	10,000
DCX124EUQ-13R-F	Automotive	C17	13	8	10,000
DCX144EU-7-F	Commercial	C20	7	8	3,000
DCX144EU-7R-F	Commercial	C20	7	8	3,000
DCX144EUQ-7-F	Automotive	C20	7	8	3,000
DCX114YU-7-F	Commercial	C14	7	8	3,000
DCX114YUQ-7-F	Automotive	C14	7	8	3,000
DCX114YUQ-13-F	Automotive	C14	13	8	10,000
DCX114YUQ-13R-F	Automotive	C14	13	8	10,000
DCX123JU-7-F	Commercial	C06	7	8	3,000
DCX114EU-7-F	Commercial	C13	7	8	3,000
DCX114EUQ-7-F	Automotive	C13	7	8	3,000
DCX114EUQ-13-F	Automotive	C13	13	8	10,000
DCX143TU-7-F	Commercial	C07	7	8	3,000
DCX143EU-7-F	Commercial	C08	7	8	3,000
DCX114TU-7-F	Commercial	C12	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 3. -7R and -13R are parts rotated in the pocket tape by 180°. For packaging details, go to our website at <http://www.diodes.com>.
 4. Products with Q-suffix are automotive grade. Automotive products are electrical and thermal the same as the commercial, except where specified.

Marking Information



CXX = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: X = 2010)
 M = Month (ex: 9 = September)

Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017
Code	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings NPN Section @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage <Pin: (6) to (1)>	V _{CC}	50	V
Input Voltage <Pin: (2) to (1)>	V _{IN}	DCX124EU -10 to +40 DCX144EU -10 to +40 DCX114YU -6 to +40 DCX123JU -5 to +12 DCX114EU -10 to +40 DCX143TU -5V max DCX143EU -10 to +30 DCX114TU -5V max	V
Output Current	I _O	DCX124EU 30 DCX144EU 30 DCX114YU 70 DCX123JU 100 DCX114EU 50 DCX143TU 100 DCX143EU 100 DCX114TU 100	mA
Output Current	I _C (Max)	100	mA

Maximum Ratings PNP Section @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage <Pin: (4) to (3)>	V _{CC}	50	V
Input Voltage <Pin: (5) to (4)>	V _{IN}	DCX124EU +10 to -40 DCX144EU +10 to -40 DCX114YU +6 to -40 DCX123JU +5 to -12 DCX114EU +10 to -40 DCX143TU +5V max DCX143EU +10 to -30 DCX114TU +5V max	V
Output Current	I _O	DCX124EU -30 DCX144EU -30 DCX114YU -70 DCX123JU -100 DCX114EU -50 DCX143TU -100 DCX143EU -100 DCX114TU -100	mA
Output Current	I _C (Max)	-100	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5 & 6)	P _D	100	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 5. Mounted on FR4 PC Board with minimum recommended pad layout
6. 150mW per element must not be exceeded.

Electrical Characteristics NPN Section @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
R1 Only (DCX143TU & DCX114TU)							
Collector-Base Breakdown Voltage	BV _{CBO}	50	—	—	V	I _C = 50μA	
Collector-Emitter Breakdown Voltage	BV _{CEO}	50	—	—	V	I _C = 1mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	5	—	—	V	I _E = 50μA	
Collector Cutoff Current	I _{CBO}	—	—	0.5	μA	V _{CB} = 50V	
Emitter Cutoff Current	I _{EBO}	—	—	0.5	μA	V _{EB} = 4V	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	—	0.3	V	I _C /I _B = 2.5mA / 0.25mA DCX143TU I _C /I _B = 1mA / 0.1mA DCX114TU	
DC Current Transfer Ratio	h _{FE}	100	250	600	—	I _C = 1mA, V _{CE} = 5V	
Input Resistor (R ₁) Tolerance	ΔR ₁	-30	—	+30	%	—	
Gain-Bandwidth Product	f _T	—	250	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz	
R1/R2 Only							
Input Voltage	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	V _{I(off)}	0.5 0.5 0.3 0.5 0.5 0.5	1.1 1.1 - - 1.1 1.16	—	V	V _{CC} = 5V, I _O = 100μA
	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU		V _{I(on)}	—	1.9 1.9 - - 1.9 1.99		
Output Voltage	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	V _{O(on)}		—	0.1	0.3	V
Input Current	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	I _I	—	—	0.36 0.18 0.88 3.6 0.88 0.88	mA	V _I = 5V
Output Current		I _{O(off)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DCX124EU DCX124EUQ DCX144EU DCX114YU DCX114YUQ DCX123JU DCX114EU DCX143EU	G _I	56 60 68 68 80 80 30 50	—	—	—	V _O = 5V, I _O = 5mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 10mA
Input Resistor (R ₁) Tolerance	ΔR ₁	-30	—	+30	%	—	
Resistance Ratio Tolerance	R ₂ /R ₁	-20	—	+20	%	—	
Gain-Bandwidth Product	f _T	—	250	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz	

Electrical Characteristics PNP Section @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
R1 Only (DCX143TU & DCX114TU)							
Collector-Base Breakdown Voltage		BV _{CBO}	-50	—	—	V	I _C = -50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	-50	—	—	V	I _C = -1mA
Emitter-Base Breakdown Voltage		BV _{EBO}	-5	—	—	V	I _E = -50μA
Collector Cutoff Current		I _{CBO}	—	—	-0.5	μA	V _{CB} = -50V
Emitter Cutoff Current		I _{EBO}	—	—	-0.5	μA	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	—	—	-0.3	V	I _C /I _B = 2.5mA / 0.25mA DCX143TU I _C /I _B = 1mA / 0.1mA DCX114TU
DC Current Transfer Ratio		h _{FE}	100	250	600	—	I _C = -1mA, V _{CE} = -5V
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz
R1/R2 Only							
Input Voltage	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	V _{I(off)}	-0.5 -0.5 -0.3 -0.5 -0.5 -0.5	-1.1 -1.1 - - -1.1 -1.16	—	—	V _{CC} = -5V, I _O = -100μA
	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	V _{I(on)}	—	-1.9 -1.9 - - -1.9 -2.5	-3.0 -3.0 -1.4 -1.1 -3.0 -3.0	V	V _O = -0.3, I _O = -5mA V _O = -0.3, I _O = -2mA V _O = -0.3, I _O = -1mA V _O = -0.3, I _O = -5mA V _O = -0.3, I _O = -10mA V _O = -0.3, I _O = -20mA
Output Voltage	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	V _{O(on)}	—	-0.1	-0.3	V	I _O /I _I = -10mA / -0.5mA I _O /I _I = -10mA / -0.5mA I _O /I _I = -5mA / -0.25mA I _O /I _I = -5mA / -0.25mA I _O /I _I = -10mA / -0.5mA I _O /I _I = -10mA / -0.5mA
Input Current	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	I _I	—	—	-0.36 -0.18 -0.88 -3.6 -0.88 -0.88	mA	V _I = -5V
Output Current		I _{O(off)}	—	—	-0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DCX124EU DCX124EUQ DCX144EU DCX114YU DCX114YUQ DCX123JU DCX114EU DCX143EU	G _I	56 60 68 68 80 80 30 40	—	—	—	V _O = -5V, I _O = -5mA V _O = -5V, I _O = -5mA V _O = -5V, I _O = -5mA V _O = -5V, I _O = -10mA V _O = -5V, I _O = -10mA V _O = -5V, I _O = -10mA V _O = -5V, I _O = -5mA V _O = -5V, I _O = -10mA
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Resistance Ratio Tolerance		R ₂ /R ₁	-20	—	+20	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Typical Curves – Total Device



Fig. 1 Power Derating Curve

Typical Curves – DCX123JU PNP Section



Fig. 2 Typical $V_{CE(SAT)}$ vs. I_C



Fig. 3 Typical DC Current Gain



Fig. 4 Typical Output Capacitance



Fig. 5 Typical Collector Current vs. Input Voltage

Typical Curves – DCX123JU PNP Section (cont.)

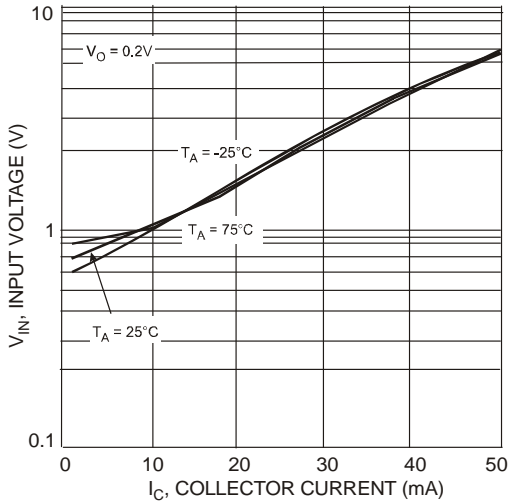


Fig. 6 Typical Input Voltage vs. Collector Current

Typical Curves – DCX123JU NPN Section



Fig. 7 Typical $V_{CE(SAT)}$ vs. I_C

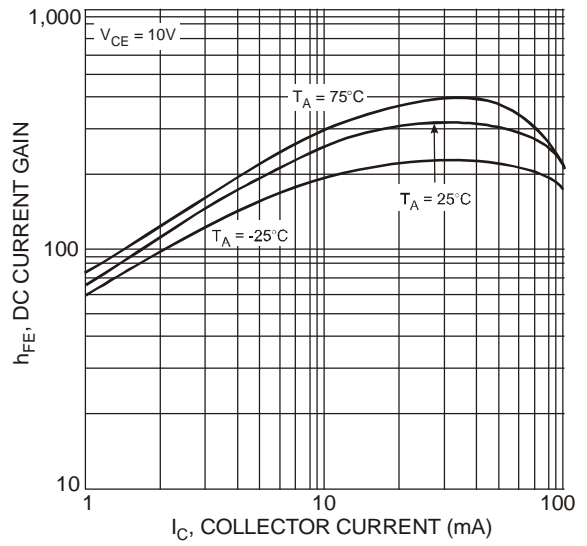


Fig. 8 Typical DC Current Gain

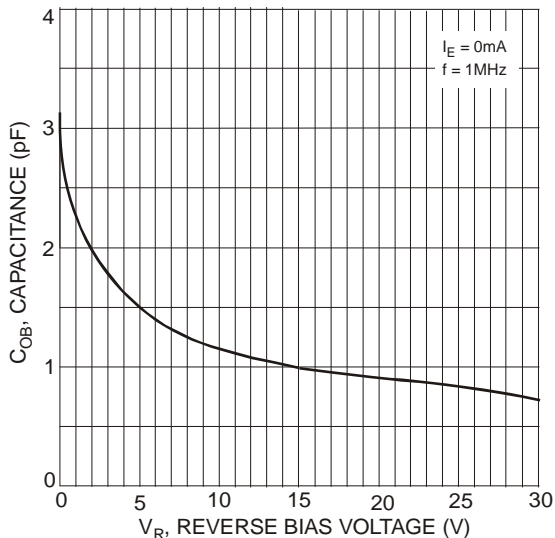


Fig. 9 Typical Output Capacitance

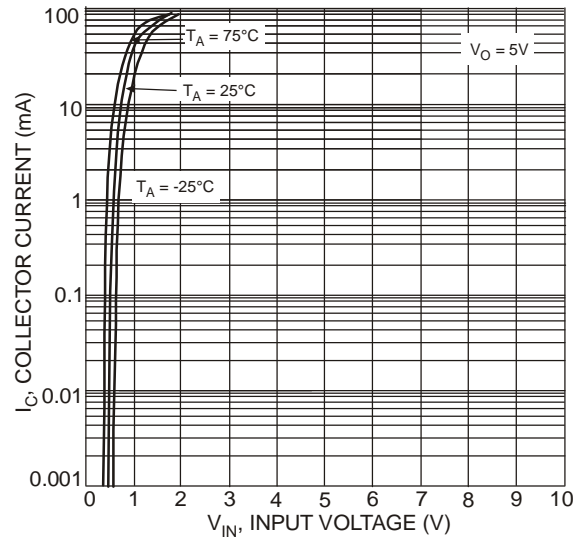


Fig. 10 Typical Collector Current vs. Input Voltage

Typical Curves – DCX123JU NPN Section (cont.)

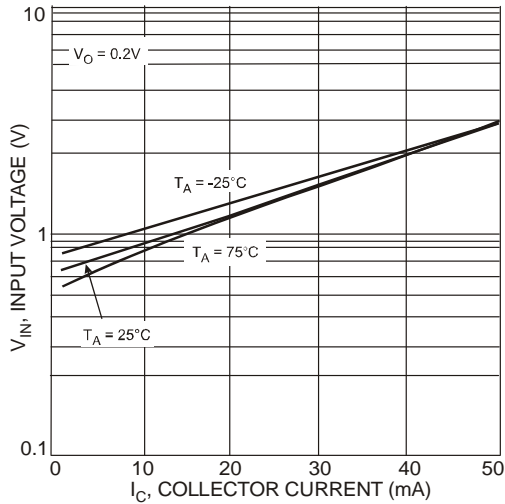


Fig. 11 Typical Input Voltage vs. Collector Current

Typical Curves – DCX143EU PNP Section

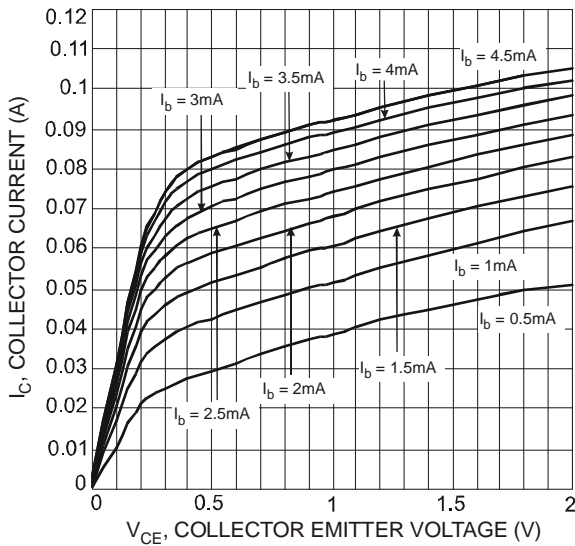


Fig. 12 Typical V_{CE} vs. I_C

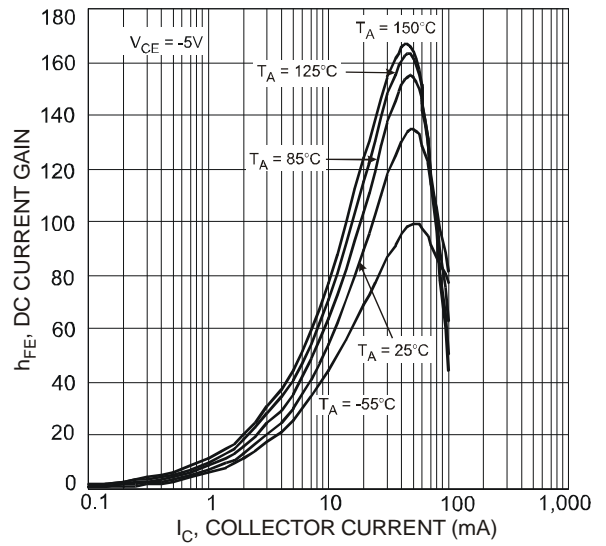


Fig. 13 Typical DC Current Gain



Fig. 14 Typical $V_{CE(SAT)}$ vs. I_C

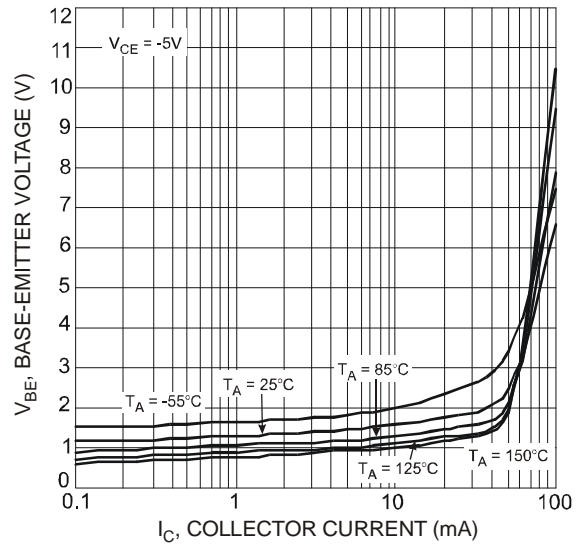


Fig. 15 Typical V_{BE} vs. I_C

Typical Curves – DCX143EU PNP Section (cont.)



Fig. 16 Typical $V_{BE(SAT)}$ vs. I_C

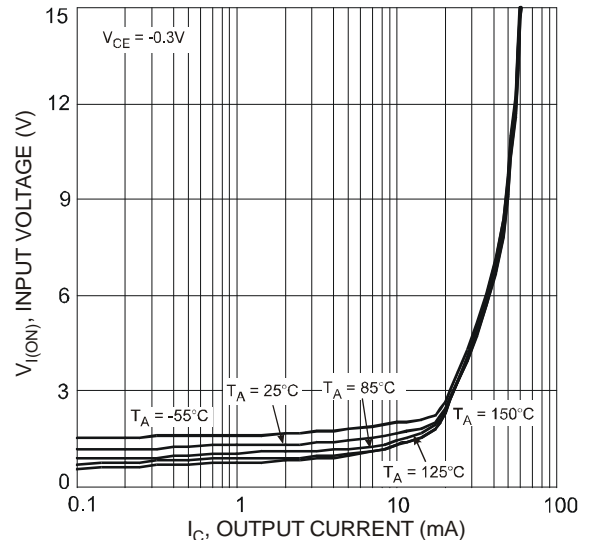


Fig. 17 Typical $V_{I(ON)}$ vs. I_C

Typical Curves – DCX143EU NPN Section



Fig. 18 Typical V_{CE} vs. I_C



Fig. 19 Typical DC Current Gain



Fig. 20 Typical $V_{CE(SAT)}$ vs. I_C

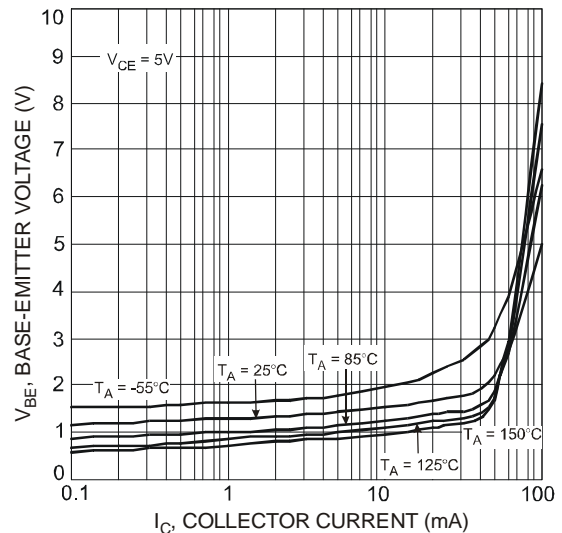


Fig. 21 Typical V_{BE} vs. I_C

Typical Curves – DCX143EU NPN Section (cont.)

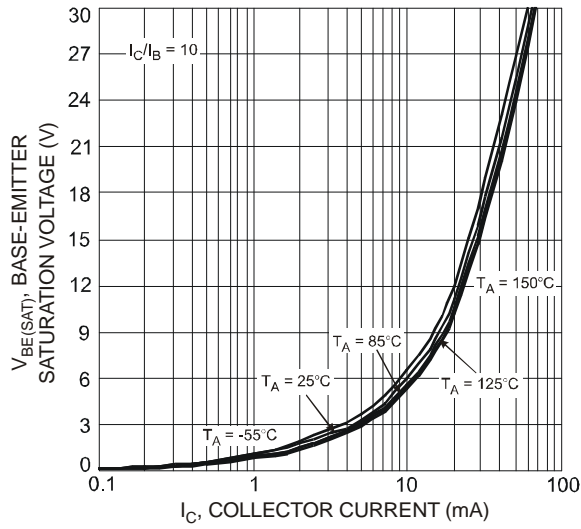


Fig. 22 Typical $V_{BE(SAT)}$ vs. I_C



Fig. 23 Typical $V_{I(ON)}$ vs. I_C

Typical Curves – DCX114TU PNP Section



Fig. 24 Typical $V_{CE(SAT)}$ vs. I_C



Fig. 25 Typical DC Current Gain

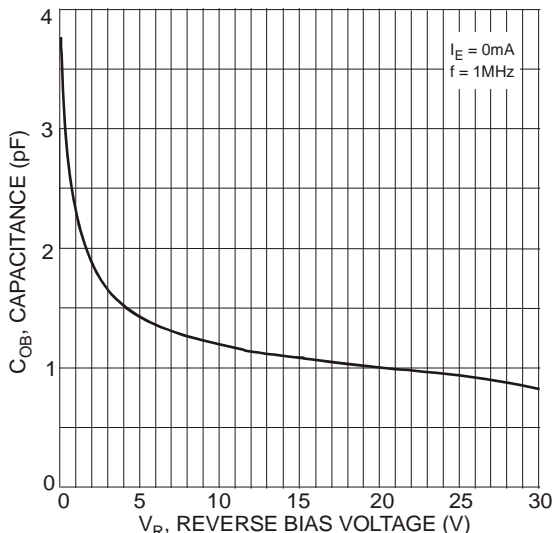


Fig. 26 Typical Output Capacitance



Fig. 27 Typical Collector Current vs. Input Voltage

Typical Curves – DCX114TU PNP Section (cont.)



Fig. 28 Typical Input Voltage vs. Collector Current

Typical Curves – DCX114TU NPN Section

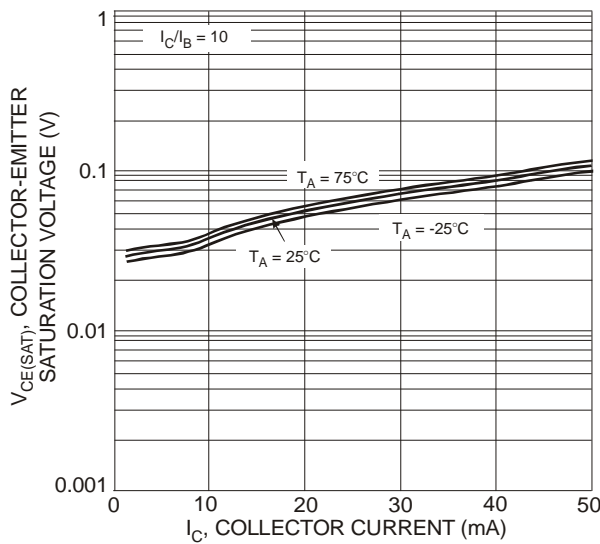


Fig. 29 Typical $V_{CE(SAT)}$ vs. I_C

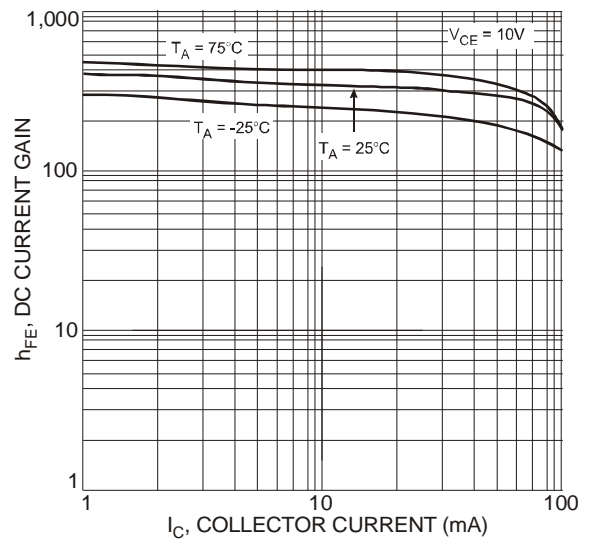


Fig. 30 Typical DC Current Gain



Fig. 31 Typical Output Capacitance



Fig. 32 Typical Collector Current vs. Input Voltage

Typical Curves – DCX114TU NPN Section (cont.)



Fig. 33 Typical Input Voltage vs. Collector Current

Package Outline Dimensions



SOT363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2012, Diodes Incorporated

www.diodes.com

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru